Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Glass **Overall Length:** Between 0.026 inches and 0.030 inches **Overall Width:** Between 0.006 inches and 0.010 inches **Function For Which Designed:** Detector **Mounting Method:** Press fit **Criticality Code Justification:** Feat Voltage Rating In Volts Per Characteristic: 4.0 breakdown voltage, instantaneous **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector preset Maximum Operating Tempurature Per Measurement Point: 175.0 degrees celsius junction **Special Features:** Hardness critical process; junction pattern arrangement: pin Shelf Life: N/a Unit Of Measure: **Demilitarization:** Yes - demil/mli Fiig: A110a0
